

General Description

The AP2210 is a 300mA ULDO regulator which provides very low noise, ultra low dropout voltage (typically 250mV at 300mA), very low standby current (1 μ A maximum) and excellent power supply ripple rejection (PSRR 75dB at 100Hz) in battery powered applications, such as handsets, PDAs and in noise sensitive applications, such as RF electronics.

The AP2210 also features individual logic compatible enable/shutdown control inputs, a low power shutdown mode for extended battery life, over current protection, over temperature protection, as well as reversed-battery protection.

The AP2210 has 2.5V, 2.8V, 3.0V, 3.3V, 3.6V, 4.0V, 5.0V and ADJ versions.

The AP2210 is available in space saving SOT-23-3 and SOT-23-5 packages.

Data Sheet

AP2210

Features

- Up to 300mA Output Current
- Excellent ESR Stability
- Low Standby Current
- Low Dropout Voltage: V_{DROP}=250mV at 300mA
- High Output Accuracy: $\pm 1\%$
- Good Ripple Rejection Ability: 75dB at 100Hz and I_{OUT} =100 μ A
- Tight Load and Line Regulation
- Low Temperature Coefficient
- Over Current Protection
- Thermal Protection
- Reverse-battery Protection
- Logic-controlled Enable

Applications

- Cellular Phones
- Cordless Phones
- Wireless Communicators
- PDAs/Palmtops
- PC Mother Board
- Consumer Electronics



Figure 1. Package Types of AP2210



300mA RF ULDO REGULATOR

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Pin Configuration





K Package





Pin Description

Pin Nu	umber	D , N	Function
SOT-23-3	B SOT-23-5 Pin Name		runction
1	2	GND	Ground
2	5	VOUT	Regulated output voltage
3	1	VIN	Input voltage
	3	EN	Enable input: CMOS or TTL compatible input. Logic high=enable, logic low=shutdown
	4	BYP/ADJ	Bypass capacitor for low noise operation/Adjustable Output



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Functional Block Diagram







Figure 3. Functional Block Diagram of AP2210



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Ordering Information



Deshare	Temperature	Part I	Number	Mark	ting ID	Packing
Package	Range	Lead Free	Green	Lead Free	Green	Туре
		AP2210N-2.5TRE1	AP2210N-2.5TRG1	EH2	GH2	Tape & Reel
		AP2210N-2.8TRE1	AP2210N-2.8TRG1	EH3	GH3	Tape & Reel
		AP2210N-3.0TRE1	AP2210N-3.0TRG1	EH4	GH4	Tape & Reel
SOT-23-3	-40 to 125°C	AP2210N-3.3TRE1	AP2210N-3.3TRG1	EH5	GH5	Tape & Reel
			AP2210N-3.6TRG1		GB7	Tape & Reel
			AP2210N-4.0TRG1		GC7	Tape & Reel
			AP2210N-5.0TRG1		GH9	Tape & Reel
		AP2210K-2.5TRE1	AP2210K-2.5TRG1	E5C	G5C	Tape & Reel
		AP2210K-2.8TRE1	AP2210K-2.8TRG1	E5F	G5F	Tape & Reel
		AP2210K-3.0TRE1	AP2210K-3.0TRG1	E5H	G5H	Tape & Reel
SOT-23-5	40 - 10500	AP2210K-3.3TRE1	AP2210K-3.3TRG1	E5K	G5K	Tape & Reel
501-25-5	-40 to 125°C		AP2210K-3.6TRG1		G5I	Tape & Reel
			AP2210K-4.0TRG1		G5J	Tape & Reel
			AP2210K-5.0TRG1		G5L	Tape & Reel
			AP2210K-ADJTRG1		G5M	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.



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Absolute Maximum Ratings (Note 1)

Parameter	Symbol		Value	Unit		
Supply Input Voltage	V _{IN}		15	v		
Enable Input Voltage	V _{EN}		15			
Power Dissipation	P _D	Internally Limite	ed (Thermal Protection)	W		
Lead Temperature (Soldering, 10sec)	T _{LEAD}		260			
Junction Temperature	T _J		150	°C		
Storage Temperature	T _{STG}	-(55 to 150	°C		
ESD (Machine Model)	ESD		300			
	Â	SOT-23-3	200	0		
Thermal Resistance (No Heatsink)	θ_{JA}	SOT-23-5	200	°C/W		

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Input Voltage	V _{IN}	2.5	13.2	V
Enable Input Voltage	V _{EN}	0	13.2	V
Operating Junction Temperature	TJ	-40	125	°C



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Electrical Characteristics (Continued) AP2210-2.5 Electrical Characteristics

 $V_{IN}=3.5V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_J=25^{o}C, \textbf{Bold} \text{ typeface applies over } -40^{o}C \leq T_J \leq 125^{o}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified	-1		1	%
Output Voltage Accuracy	4,001,,001	V _{OUT}	-2		2	/0
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		µV/ºC
Temperature Coefficient (Note 3)	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			48		ppm/°C
Line Regulation	V _{RLINE}	V _{IN} =3.5V to 13.2V		1.5	4.5	
	KEINE	114			12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)					30	mV
		I _{OUT} =100μA		15	50	
					70	
Dropout Voltage (Note 5)		$I_{OUT}=50mA$ $I_{OUT}=100mA$ $I_{OUT}=150mA$ $I_{OUT}=300mA$		110	150	
					230	
	V _{DROP}			140	250	mV
					300	
				165	275	
					350	
				250	400	
					500	
Standby Current	I _{STD}	$V_{EN} \leq 0.4V$ (shutdown)		0.01	1	μA
		$V_{EN} \le 0.18V$ (shutdown)			5	
		V _{EN} ≥2.0V, I _{OUT} =100µA		100	150	-
					180	μΑ
		V _{EN} ≥2.0V, I _{OUT} =50mA		350	600	
Ground Pin Current (Note 6)	I _{GND}				800	
(1000 0)		$V_{EN} \ge 2.0V$, $I_{OUT} = 150mA$		1.3	1.9	
					2.5	mA
		V _{EN} ≥2.0V, I _{OUT} =300mA		4	10	
					15	
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100µA		75		dB
Current Limit	I _{LIMIT}	V _{OUT} =0V		450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2µF, 100pF from BYP to GND		260		nV/\sqrt{Hz}

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Electrical Characteristics (Continued) AP2210-2.5 Electrical Characteristics

 V_{IN} =3.5V, I_{OUT} =100 μ A, C_{IN} =1.0 μ F, C_{OUT} =2.2 μ F, V_{EN} ≥2.0V, T_J =25°C, **Bold** typeface applies over -40°C≤ T_J ≤125°C (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Enable Input Logic-low Voltage	V _{IL}	Regulator shutdown			0.4	V
Enable input Eogle four voluge	1L	regulator shatao wh			0.18	·
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	$V_{IL} \leq 0.4 V$		0.01	1	μΑ
Zhuere input Zegie iew current	IL	$V_{IL} \leq 0.18V$			2	por 1
Enable Input Logic-high Current	I _{IH}	V _{IL} ≥2.0V		5	20	μA
Endore input Eogle ingli Current	IT	V _{IL} ≥2.0V			25	M2 1

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^{\circ}C$) or 2% (- $40^{\circ}C\leq T_{I}\leq 125^{\circ}C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



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Electrical Characteristics (Continued) AP2210-2.8 Electrical Characteristics

 $V_{IN}=3.8V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_J=25^{o}C, \textbf{Bold} \text{ typeface applies over } -40^{o}C \leq T_J \leq 125^{o}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified	-1		1	%
Output Voltage Accuracy		V _{OUT}	-2		2	/0
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		µV/ºC
Temperature Coefficient (Note 3)	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			42.8		ppm/ºC
Line Regulation	V _{RLINE}	V _{IN} =3.8V to 13.2V		1.5	4.5	
	KEINE	114			12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)		001			30	mV
		I _{OUT} =100μA		15	50	
					70	
Dropout Voltage (Note 5)		I _{OUT} =50mA		110	150	
					230	mV
	V _{DROP}	I _{OUT} =100mA I _{OUT} =150mA I _{OUT} =300mA		140	250	
					300	
				165	275	
					350	
				250	400	
					500	
Standby Current	I _{STD}	$V_{EN} \le 0.4V$ (shutdown)		0.01	1	μΑ
-		V _{EN} ≤0.18V (shutdown)			5	-
		V _{EN} ≥2.0V, I _{OUT} =100µA		100	150	
					180	μΑ
		V _{EN} ≥2.0V, I _{OUT} =50mA		350	600	F
Ground Pin Current	I _{GND}				800	
(Note 6)		V _{EN} ≥2.0V, I _{OUT} =150mA		1.3	1.9	- mA
					2.5	
		V _{EN} ≥2.0V, I _{OUT} =300mA		4	10	
					15	
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100µA		75		dB
Current Limit	I _{LIMIT}	V _{OUT} =0V		450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2μF, 100pF from BYP to GND		260		nV/\sqrt{Hz}

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Electrical Characteristics (Continued) AP2210-2.8 Electrical Characteristics

 V_{IN} =3.8V, I_{OUT} =100 μ A, C_{IN} =1.0 μ F, C_{OUT} =2.2 μ F, V_{EN} ≥2.0V, T_J =25°C, **Bold** typeface applies over -40°C≤ T_J ≤125°C (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Enable Input Logic-low Voltage	V _{IL}	Regulator shutdown			0.4	V
Enable input Eogle four voluge	1L	regulator shatao wh			0.18	·
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	$V_{IL} \leq 0.4 V$		0.01	1	μΑ
Zhuere input Zegie iew current	IL	$V_{IL} \leq 0.18V$			2	per 1
Enable Input Logic-high Current	I _{IH}	V _{IL} ≥2.0V		5	20	μA
Endote input Eogle ingli Current	IT	V _{IL} ≥2.0V			25	M2 1

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^{\circ}C$) or 2% (- $40^{\circ}C\leq T_{I}\leq 125^{\circ}C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



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Electrical Characteristics (Continued) AP2210-3.0 Electrical Characteristics

 $V_{IN}=4V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_J=25^{\circ}C, \text{ Bold typeface applies over } -40^{\circ}C \leq T_J \leq 125^{\circ}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified	-1		1	%
Sulput Voluge Meetiney		V _{OUT}	-2		2	70
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		µV/ºC
Temperature Coefficient (Note 3) Line Regulation Load Regulation (Note 4) Dropout Voltage (Note 5)	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			40		ppm/°C
Line Regulation	V _{RLINE}	V _{IN} =4V to 13.2V		1.5	4.5	
	KLINE	111			12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)	REORD	001			30	mV
		I _{OUT} =100μA		15	50	
					70	
Dropout Voltage (Note 5)		I _{OUT} =50mA		110	150	
					230	mV
	V _{DROP}	I _{OUT} =100mA		140	250	
					300	
		I _{OUT} =150mA		165	275	
		I _{OUT} =300mA		250	275 350 400 500	
					500	
Standby Current	I _{STD}	$V_{EN} \leq 0.4 V \text{ (shutdown)}$		0.01	1	μΑ
		V _{EN} ≤0.18V (shutdown)			5	
		V _{EN} ≥2.0V, I _{OUT} =100µA		100	150	
					180	μA
		V _{EN} ≥2.0V, I _{OUT} =50mA		350	600	
Ground Pin Current	I _{GND}				800	
(Note 6)		V _{EN} ≥2.0V, I _{OUT} =150mA		1.3	1.9	
					2.5	mA
		V _{EN} ≥2.0V, I _{OUT} =300mA		4	10	
			_		15	
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100μA	_	75		dB
Current Limit	I _{LIMIT}	V _{OUT} =0V	_	450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2µF, 100pF from BYP to GND		260		nV/\sqrt{Hz}

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Electrical Characteristics (Continued) AP2210-3.0 Electrical Characteristics

 $V_{IN}=4V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_{J}=25^{\circ}C, \text{ Bold typeface applies over } -40^{\circ}C \leq T_{J} \leq 125^{\circ}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Enable Input Logic-low Voltage	V _{IL}	Regulator shutdown			0.4	V
Enable input Logie iow voltage	1L	regulator shatao wh			0.18	·
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	$V_{IL} \leq 0.4V$		0.01	1	μA
Linere input Legie iew current	IL	V _{IL} ≤0.18V			2	per 1
Enable Input Logic-high Current	I _{IH}	V _{IL} ≥2.0V		5	20	μA
Endore input Bogie ingli Current	Ш	V _{IL} ≥2.0V			25	M2 1

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^{\circ}C$) or 2% (- $40^{\circ}C\leq T_{I}\leq 125^{\circ}C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



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Electrical Characteristics (Continued) AP2210-3.3 Electrical Characteristics

 V_{IN} =4.3V, I_{OUT} =100 μ A, C_{IN} =1.0 μ F, C_{OUT} =2.2 μ F, V_{EN} ≥2.0V, T_J =25°C, **Bold** typeface applies over -40°C≤ T_J ≤125°C (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT} / V_{OUT}$	Variation from specified	-1		1	%
Sulput Voluge Meetiney	001 001	V _{OUT}	-2		2	70
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		µV/ºC
Output Voltage Accuracy Output Voltage Temperature Coefficient (Note 3) Line Regulation Load Regulation (Note 4) Dropout Voltage (Note 5) Standby Current Ground Pin Current	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			36.3		ppm/°C
Line Regulation	V _{RLINE}	V _{IN} =4.3V to 13.2V		1.5	4.5	
	KLINE				12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)	REOND	001			30	mV
		I _{OUT} =100μA		15	50	
					70	
Dropout Voltage (Note 5)		I _{OUT} =50mA		110	150	
					230	mV
	V _{DROP}	I _{OUT} =100mA		140	250	
		I _{OUT} =150mA			300	
				165	275	
					350	
		I _{OUT} =300mA		250	400	
				0.01	500	
Standby Current	I _{STD}	$V_{\rm EN} \leq 0.4 V \text{ (shutdown)}$		0.01	1	μΑ
		$V_{EN} \le 0.18V$ (shutdown)		100	5	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 100 \mu A$		100	150	
				350	180 600	μΑ
Ground Pin Current		V _{EN} ≥2.0V, I _{OUT} =50mA		550	800	
(Note 6)	I _{GND}			1.3	1.9	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 150mA$		1.5	2.5	mA
				4	10	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 300mA$			15	
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100µA		75		dB
Current Limit	I _{LIMIT}	V _{OUT} =0V		450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2µF, 100pF from BYP to GND		260		nV/\sqrt{Hz}

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Electrical Characteristics (Continued) AP2210-3.3 Electrical Characteristics

 V_{IN} =4.3V, I_{OUT} =100 μ A, C_{IN} =1.0 μ F, C_{OUT} =2.2 μ F, V_{EN} ≥2.0V, T_J =25°C, **Bold** typeface applies over -40°C≤ T_J ≤125°C (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Enable Input Logic-low Voltage	V _{IL}	Regulator shutdown			0.4	V
Enable input Eogle four voluge	1L	regulator shatao wh			0.18	·
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	$V_{IL} \leq 0.4 V$		0.01	1	μΑ
Zhuere input Zegie iew current	IL	$V_{IL} \leq 0.18V$			2	per 1
Enable Input Logic-high Current	I _{IH}	V _{IL} ≥2.0V		5	20	μA
Endote input Eogle ingli Current	IT	V _{IL} ≥2.0V			25	M2 1

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^{\circ}C$) or 2% (- $40^{\circ}C \le T_I \le 125^{\circ}C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



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Electrical Characteristics (Continued) AP2210-3.6 Electrical Characteristics

 $V_{IN}=4.6V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_J=25^{o}C, \textbf{Bold} \text{ typeface applies over } -40^{o}C \leq T_J \leq 125^{o}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified V_{OUT}	-1		1	%
			-2		2	70
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		µV/°C
Temperature Coefficient (Note 3)	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			48		ppm/°C
Line Regulation	V _{RLINE}	V _{IN} =4.6V to 13.2V		1.5	4.5	
2mil regulation	KEINE				12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)	REORD	001			30	mV
		I _{OUT} =100μA		15	50	
					70	
		I _{OUT} =50mA		110	150	
					230	
Dropout Voltage (Note 5)	V _{DROP}	I _{OUT} =100mA		140	250	mV
					300	
		I _{OUT} =150mA		165 275		
				350	-	
		I _{OUT} =300mA		250	400	
					500	
Standby Current	I _{STD}	$V_{EN} \leq 0.4 V \text{ (shutdown)}$		0.01	1	μΑ
		$V_{EN} \leq 0.18V \text{ (shutdown)}$			5	
		V _{EN} ≥2.0V, I _{OUT} =100µA		100	150	
					180	μΑ
		V _{EN} ≥2.0V, I _{OUT} =50mA		350	600	
Ground Pin Current (Note 6)	I _{GND}				800	μA
(10000)		$V_{EN} \ge 2.0V$, $I_{OUT} = 150mA$		1.3	1.9	
					2.5	mA
		$V_{EN} \ge 2.0V$, $I_{OUT} = 300mA$		4	10	
Disels Deised	DODD	C 10011 L 100 A		75	15	10
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100μA		75	000	
Current Limit	I _{LIMIT}	V _{OUT} =0V		450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2µF, 100pF from BYP to GND		260		nV/\sqrt{Hz}

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Electrical Characteristics (Continued) AP2210-3.6 Electrical Characteristics

 V_{IN} =4.6V, I_{OUT} =100 μ A, C_{IN} =1.0 μ F, C_{OUT} =2.2 μ F, V_{EN} ≥2.0V, T_J =25°C, **Bold** typeface applies over -40°C≤ T_J ≤125°C (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Enable Input Logic-low Voltage	V _{IL}	Regulator shutdown			0.4	v
Endole input Logie low voltage	1L	Regulator enabled 2.0	0.18	·		
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	$V_{IL} \le 0.4 V$		0.01	1	μA
	-IL	V _{IL} ≤0.18V			2	- p
Enable Input Logic-high Current	I _{IH}	V _{IL} ≥2.0V		5	20	μA
	-10	$V_{IL} \ge 2.0 V$			25	μ

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^{\circ}C$) or 2% (- $40^{\circ}C\leq T_{I}\leq 125^{\circ}C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210

Electrical Characteristics (Continued) AP2210-4.0 Electrical Characteristics

 $V_{IN}=5.0V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_{J}=25^{o}C, \textbf{Bold} \text{ typeface applies over } -40^{o}C \leq T_{J} \leq 125^{o}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified V_{OUT}	-1		1	%
			-2		2	70
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		µV/°C
Temperature Coefficient (Note 3)	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			48		ppm/°C
Line Regulation	V _{RLINE}	V _{IN} =5.0V to 13.2V		1.5	4.5	
	KEINE	114			12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)					30	mV
		I _{OUT} =100μA		15	50	
					70	
		I _{OUT} =50mA		110	150	
					230	
Dropout Voltage (Note 5)	V _{DROP}	I _{OUT} =100mA		140 25	250	mV
. [· · · · · · · · · · · · · · · · · ·					300	
		I _{OUT} =150mA		165 275		
					350	_
		I _{OUT} =300mA		250	400	
					500	
Standby Current	I _{STD}	$V_{EN} \le 0.4V$ (shutdown)		0.01	1	μA
		V _{EN} ≤0.18V (shutdown)			5	
		V _{EN} ≥2.0V, I _{OUT} =100µA		100	150	
					180	μΑ
		V _{EN} ≥2.0V, I _{OUT} =50mA		350	600	
Ground Pin Current	I _{GND}				800	
(Note 6)		V _{EN} ≥2.0V, I _{OUT} =150mA		1.3	1.9	
					2.5	mA
		V _{EN} ≥2.0V, I _{OUT} =300mA		4	10	
					15	
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100µA		75		dB
Current Limit	I _{LIMIT}	V _{OUT} =0V		450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2μF, 100pF from BYP to GND		260		nV/\sqrt{Hz}

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Electrical Characteristics (Continued) AP2210-4.0 Electrical Characteristics

 V_{IN} =5.0V, I_{OUT} =100 μ A, C_{IN} =1.0 μ F, C_{OUT} =2.2 μ F, V_{EN} ≥2.0V, T_J =25°C, **Bold** typeface applies over -40°C≤ T_J ≤125°C (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Enable Input Logic-low Voltage	V _{IL}	Regulator shutdown			0.4	v
Enable input Eogle four voluge	1L				0.18	·
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	$V_{IL} \leq 0.4 V$		0.01	1	μΑ
	-IL	$V_{IL} \leq 0.18V$			2	
Enable Input Logic-high Current	I _{IH}	V _{IL} ≥2.0V		5	20	μA
	IT	V _{IL} ≥2.0V			25	M2 1

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^{\circ}C$) or 2% (- $40^{\circ}C\leq T_{I}\leq 125^{\circ}C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210

Electrical Characteristics (Continued) AP2210-5.0 Electrical Characteristics

 $V_{IN}=6.0V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_J=25^{o}C, \textbf{Bold} \text{ typeface applies over } -40^{o}C \leq T_J \leq 125^{o}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified V_{OUT}	-1		1	%
			-2		2	70
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		µV/ºC
Temperature Coefficient (Note 3)	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			48		ppm/°C
Line Regulation	V _{RLINE}	V _{IN} =6.0V to 13.2V		1.5	4.5	
	' KLINE	114			12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)		001			30	mV
		I _{OUT} =100μA		15	50	
					70	
		I _{OUT} =50mA		110	150	
					230	
Dropout Voltage (Note 5)	V _{DROP}	I _{OUT} =100mA		140	250	mV
. [· · · · · · · · · · · · · · · · · ·					300	
		I _{OUT} =150mA	165	275	-	
					350	
		I _{OUT} =300mA		250	400	
					500	
Standby Current	I _{STD}	$V_{EN} \le 0.4V$ (shutdown)		0.01	1	μΑ
-	515	V _{EN} ≤0.18V (shutdown)			5	
		V _{EN} ≥2.0V, I _{OUT} =100µA		100	150	
					180	μA μA
		V _{EN} ≥2.0V, I _{OUT} =50mA		350	600	
Ground Pin Current	I _{GND}				800	
(Note 6)		V _{EN} ≥2.0V, I _{OUT} =150mA		1.3	1.9	
					2.5	mA
		V _{EN} ≥2.0V, I _{OUT} =300mA		4	10	
					15	
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100µA		75		dB
Current Limit	I _{LIMIT}	V _{OUT} =0V		450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2μF, 100pF from BYP to GND		260		nV/\sqrt{Hz}

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Electrical Characteristics (Continued) AP2210-5.0 Electrical Characteristics

 V_{IN} =6.0V, I_{OUT} =100 μ A, C_{IN} =1.0 μ F, C_{OUT} =2.2 μ F, V_{EN} ≥2.0V, T_J =25°C, **Bold** typeface applies over -40°C≤ T_J ≤125°C (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Enable Input Logic-low Voltage	V _{IL}	Regulator shutdown			0.4	v
Enable input Eogle four voluge	1L				0.18	·
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	$V_{IL} \leq 0.4 V$		0.01	1	μΑ
	-IL	$V_{IL} \leq 0.18V$			2	
Enable Input Logic-high Current	I _{IH}	V _{IL} ≥2.0V		5	20	μA
	IT	V _{IL} ≥2.0V			25	M2 1

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^{\circ}C$) or 2% (- $40^{\circ}C\leq T_{I}\leq 125^{\circ}C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210

Electrical Characteristics (Continued) AP2210-ADJ Electrical Characteristics

 $V_{IN}=V_{OUT}+1V, I_{OUT}=100\mu A, C_{IN}=1.0\mu F, C_{OUT}=2.2\mu F, V_{EN}\geq 2.0V, T_{J}=25^{o}C, \text{ Bold typeface applies over } -40^{o}C \leq T_{J} \leq 125^{o}C \text{ (Note 2), unless otherwise specified.}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified	-1		1	%
	001 001	V _{OUT}	-2		2	,,,
Output Voltage	$\Delta V_{OUT} / \Delta T$			120		$\mu V/^{o}C$
Temperature Coefficient (Note 3)	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			48		ppm/ ^o C
Line Regulation	V _{RLINE}	$V_{IN} = V_{OUT} + 1V$ to 13.2V		1.5	4.5	
	KEINE				12	mV
Load Regulation	V _{RLOAD}	I _{OUT} =0.1mA to 300mA		1	6	
(Note 4)	REORD	001			30	mV
Standby Current	I _{STD}	$V_{EN} \leq 0.4 V \text{ (shutdown)}$		0.01	1	μA
2	510	$V_{EN} \leq 0.18V$ (shutdown)			5	
		V _{EN} ≥2.0V, I _{OUT} =100µA		100	150	
					180	μA
Ground Pin Current		V _{EN} ≥2.0V, I _{OUT} =50mA		350	600	por I
	I _{GND}	EN			800	
(Note 6)	UND	V _{EN} ≥2.0V, I _{OUT} =150mA		1.3	1.9	
		EN TO TOT			2.5	mA
		V _{EN} ≥2.0V, I _{OUT} =300mA		4	10	IIIA
		· EN , •001 ••••			15	
Ripple Rejection	PSRR	f=100Hz, I _{OUT} =100µA		75		dB
Current Limit	I _{LIMIT}	V _{OUT} =0V		450	900	mA
Output Noise	e _{no}	I _{OUT} =50mA, C _{OUT} =2.2µF, 100pF from BYP to GND		260		nV/\sqrt{Hz}
Enable Input Logic-low	V _{IL}	Regulator shutdown			0.4	v
Voltage	* IL	Regulator shutdown			0.18	
Enable Input Logic-high Voltage	V _{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I _{IL}	V _{IL} ≤0.4V		0.01	1	μA
	1IL	$V_{IL} \le 0.18V$			2	
Enable Input Logic-high	I _{IH}	V _{IL} ≥2.0V		5	20	шА
Current	*1H	V _{IL} ≥2.0V			25	μA



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Electrical Characteristics (Continued) AP2210-ADJ Electrical Characteristics

 $V_{IN}=V_{OUT}+1V$, $I_{OUT}=100\mu A$, $C_{IN}=1.0\mu F$, $C_{OUT}=2.2\mu F$, $V_{EN}\ge 2.0V$, $T_J=25^{\circ}C$, **Bold** typeface applies over -40°C $\le T_J \le 125^{\circ}C$ (Note 2), unless otherwise specified.

Note 2: Specifications in bold type are limited to $-40^{\circ}C \le T_J \le 125^{\circ}C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



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300mA RF ULDO REGULATOR

Typical Performance Characteristics



Figure 4. Output Voltage vs. Junction Temperature



Figure 5. Dropout Voltage vs. Junction Temperature



Figure 6. Ground Pin Current vs. Output Current



Figure 7. Ground Pin Current vs. Junction Temperature

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Figure 8. Enable Current vs. Junction Temperature



Figure 9. Enable Voltage vs. Junction Temperature



Figure 10. Output Noise vs. Frequency





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Figure 12. Load Transient (Conditions: V_{IN}=4V, V_{EN}=2V, I_{OUT}=10mA to 300mA, C_{IN}=1.0µF, C_{OUT}=2.2µF)





Figure 13. V_{EN} vs. V_{OUT} (Conditions: V_{EN}=0 to 2V, V_{IN}=4V, I_{OUT}=30mA, C_{IN} =1.0µF, C_{OUT} =2.2µF)



Figure 15. Power Dissipation vs. Ambient Temperature

AP2210-3.0 90 V_{IN} =4V, V_{RIPPLE} =1 V_{PP} 80 I_{OUT} =10mA, C_{OUT}=2.2µF 70 60 PSRR (dB) 50 40 30 20 10 0 ∟ 10 100 1k 10k 100k 1M Frequency (Hz)

Figure 14. PSRR vs. Frequency

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Figure 16. Power Dissipation vs. Ambient Temperature

Figure 17. ESR vs. Output Current



Figure 18. ESR vs. Output Current



Figure 19. ESR vs. Output Current



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Typical Application





For Fixed Version



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Typical Application (Continued)



$$V_{OUT} = 1.25V*(1+R2/R1)$$

For Adjustable Version

Figure 20. Typical Application of AP2210 (Note 7)

Note 7: Dropout voltage is 250mV when $T_A=25^{\circ}C$. In order to obtain a normal output voltage, $V_{OUT}+0.25V$ is the minimum input voltage which will results a low PSRR, imposing a bad influence on system. Therefore, the recommended input voltage is $V_{OUT}+1V$ to 13.2V. For AP2210-3.0 version, its input voltage can be set from $4V(V_{OUT}+1V)$ to 13.2V.



Application Information

Input Capacitor

A 1 μ F minimum capacitor is recommended to be placed between V_{IN} and GND.

Output Capacitor

It is required to prevent oscillation. 1.0μ F minimum is recommended when C_{BYP} is unused. 2.2μ F minimum is recommended when C_{BYP} is 100pF. The output capacitor may be increased to improve transient response.

Noise Bypass Capacitor

Bypass capacitor is connected to the internal voltage reference. A small capacitor connected from BYP to GND make this reference quiet, resulting in a significant reduction in output noise, but the ESR stable area will be narrowed. In order to keep the output stability, it is recommended to use the bypass capacitor no more than 100pF.

The start-up speed of the AP2210 is inversely proportional to the value of reference bypass capacitor. In some cases, if output noise is not a major concern and rapid turn-on is necessary, omit $C_{\rm BYP}$ and leave BYP open.

Power Dissipation

Thermal shutdown may take place if exceeding the maximum power dissipation in application. Under all possible operating conditions, the junction tempera-

ture must be within the range specified under absolute maximum ratings to avoid thermal shutdown.

To determine if the power dissipated in the regulator reaches the maximum power dissipation (see figure 16, 17), using:

$$\begin{split} T_J &= P_D * \theta_{JA} + T_A \\ P_D &= (V_{IN} - V_{OUT}) * I_{OUT} + V_{IN} * I_{GND} \end{split}$$

Where: $T_J \leq T_{J(max)}$, $T_{J(max)}$ is absolute maximum ratings for the junction temperature; $V_{IN}*I_{GND}$ can be ignored due to its small value.

 $T_{J(max)}$ is 150°C, θ_{JA} is 200°C/W, no heatsink is required since the package alone will dissipate enough heat to satisfy these requirements unless the calculated value for power dissipation exceeds the limit.

Example (3.0V version): I_{OUT}=300mA, T_A=50°C, V_{IN(Max)} is: (150°C-50°C)/(0.3A*200°C/W)+3.0V=4.67V

Therefore, for good performance, please make sure that input voltage is less than 4.67V without heatsink when $T_A=50^{\circ}C$.



300mA RF ULDO REGULATOR

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Mechanical Dimensions

SOT-23-3

Unit: mm(inch)





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300mA RF ULDO REGULATOR

Mechanical Dimensions (Continued)

Unit: mm(inch)



SOT-23-5

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